

Trench IGBT Modules

SEMiX453GB12E4p

Features*

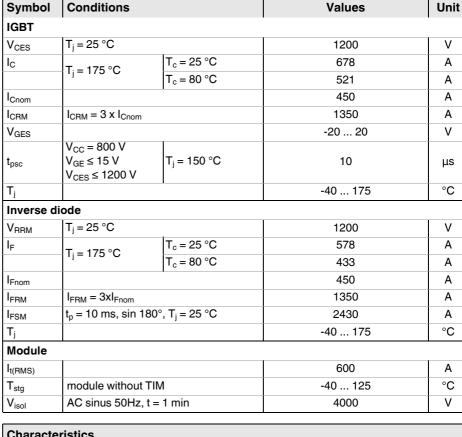
- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- · High short circuit capability
- · Press-fit pins as auxiliary contacts
- UL recognized, file no. E63532

Typical Applications

- · AC inverter drives
- UPS
- · Renewable energy systems

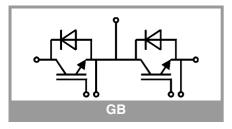
Remarks

- Product reliability results are valid for T_i=150°C
- V_{isol} between temperature sensor and power section is only 2500V
- For storage and case temperature with TIM see document "TP(*) SEMiX 3p"



Absolute Maximum Ratings

Characteristics									
Symbol	Conditions	min.	typ.	max.	Unit				
IGBT									
V	I _C = 450 A	T _j = 25 °C		1.80	2.05	V			
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.19	2.40	V			
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V			
		T _j = 150 °C		0.70	0.80	V			
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		2.2	2.6	mΩ			
		T _j = 150 °C		3.3	3.6	mΩ			
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 18 \text{ mA}$		5	5.8	6.5	V			
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$			5	mΑ				
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		27.9		nF			
C _{oes}		f = 1 MHz		1.74		nF			
C _{res}		f = 1 MHz		1.53		nF			
Q _G	V _{GE} = - 8 V+ 15 V			2550		nC			
R _{Gint}	T _j = 25 °C			1.7		Ω			
t _{d(on)}	$\begin{array}{c} \text{di/dt}_{\text{on}} = 7000 \text{ A/}\mu\text{s} \\ \text{di/dt}_{\text{off}} = 3300 \text{ A/}\mu\text{s} \end{array}$	T _j = 150 °C		160		ns			
t _r		T _j = 150 °C		60		ns			
E _{on}		T _j = 150 °C		32		mJ			
t _{d(off)}		T _j = 150 °C		480		ns			
tf		T _j = 150 °C		115		ns			
E _{off}		T _j = 150 °C		57		mJ			
R _{th(j-c)}	per IGBT				0.066	K/W			
R _{th(c-s)}	per IGBT (λ _{grease} =0	.81 W/(m*K))		0.03		K/W			
R _{th(c-s)}	per IGBT, pre-appli material		0.021		K/W				





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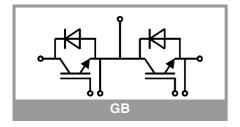
Typical Applications

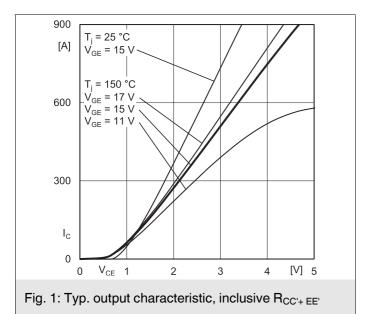
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- Renewable energy systems

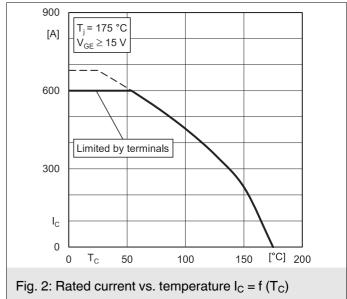
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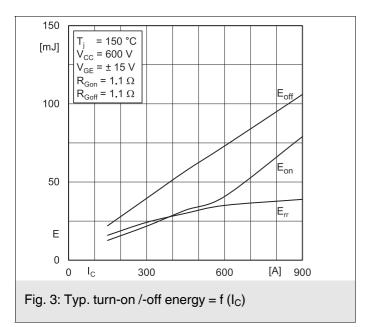
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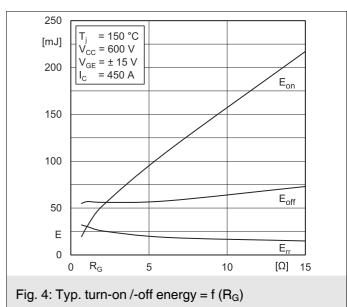
Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverse diode										
$V_F = V_{EC}$	I _F = 450 A	T _j = 25 °C		2.14	2.46	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.07	2.38	٧				
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V				
		T _j = 150 °C		0.90	1.10	V				
r _F	chiplevel	T _j = 25 °C		1.87	2.1	mΩ				
		T _j = 150 °C		2.6	2.8	mΩ				
I _{RRM}	I _F = 450 A	T _j = 150 °C		460		Α				
Q _{rr}	$di/dt_{off} = 7000 \text{ A/}\mu\text{s}$ $V_{GE} = -15 \text{ V}$	T _j = 150 °C		77		μC				
E _{rr}	$V_{CC} = 600 \text{ V}$	T _j = 150 °C		30		mJ				
R _{th(j-c)}	per diode	per diode			0.1	K/W				
R _{th(c-s)}	per diode (λ _{grease} =0.81 W/(m*K))			0.045		K/W				
R _{th(c-s)}	per diode, pre-applied phase change material			0.036		K/W				
Module										
L _{CE}				20		nH				
R _{CC'+EE'}	measured per switch	T _C = 25 °C		0.95		mΩ				
		T _C = 125 °C		1.25		mΩ				
R _{th(c-s)1}	calculated without t		0.009		K/W					
R _{th(c-s)2}	including thermal co Ts underneath mod (m*K))		0.014		K/W					
R _{th(c-s)2}	including thermal coupling, Ts underneath module, pre-applied phase change material			0.011		K/W				
Ms	to heat sink (M5)		3		6	Nm				
Mt		to terminals (M6)	3		6	Nm				
						Nm				
w					350	g				
Temperature Sensor										
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω				
B _{100/125}	$R_{(T)} = R_{100} exp[B_{100/125}(1/T-1/T_{100})]; T[K];$			3550 ±2%		К				

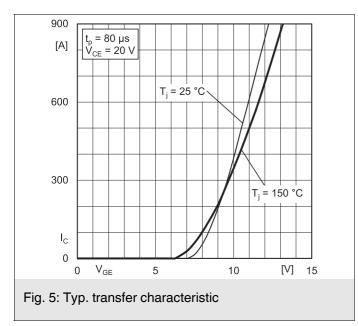


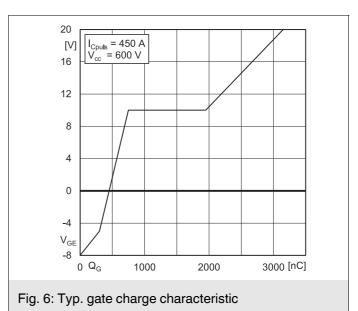


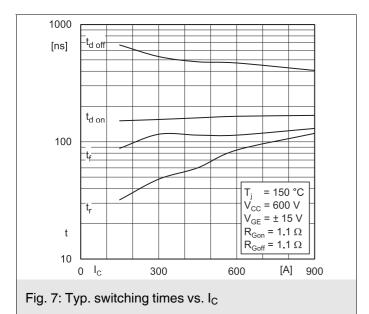


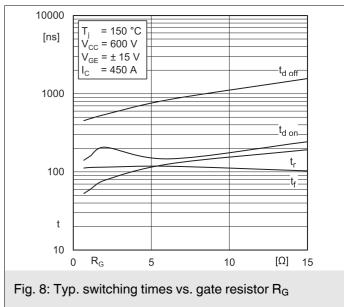


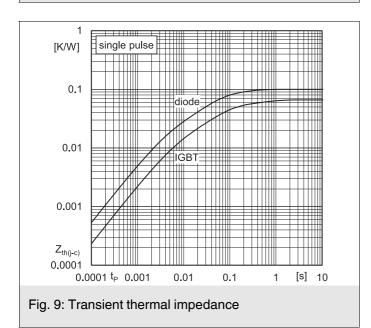


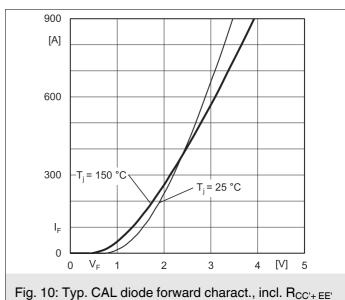


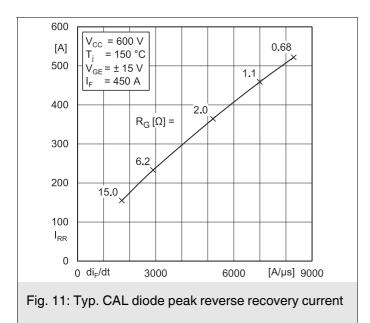


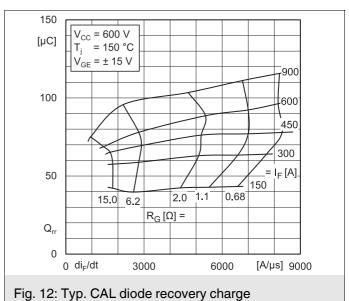


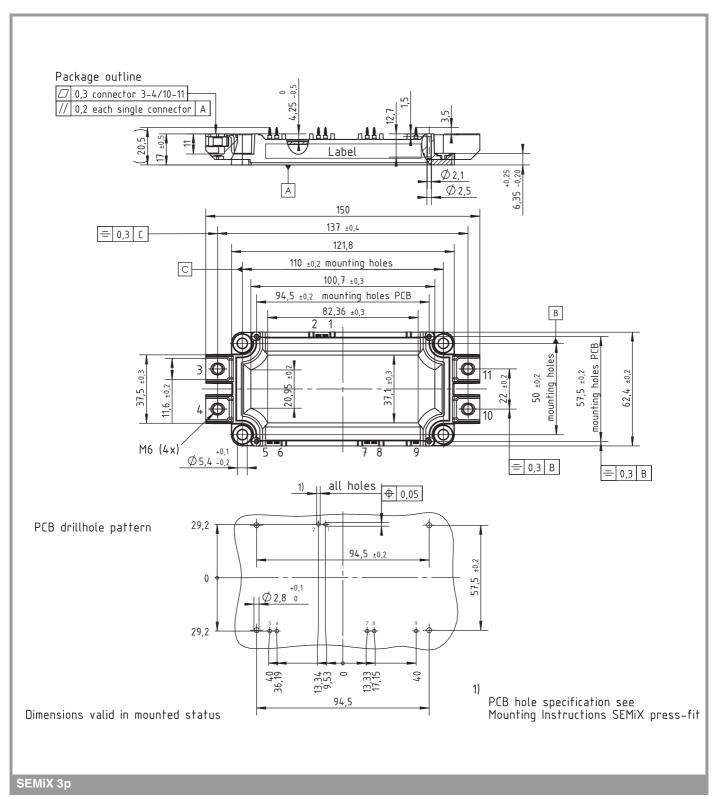


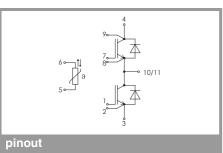












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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